NSN 5961-01-280-1055

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Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 drain to source voltage

Current Rating Per Characteristic:

14.00 amperes drain current

Power Rating Per Characteristic:

75.0 watts average off-state power dissipation

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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